Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass
Overall Length:
0.300 inches
Terminal Length:
1.500 inches
Overall Diameter:
0.107 inches
Function For Which Designed:
Voltage variable capacitor
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
Do-7
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
30.0 working peak reverse voltage, peak total value
Current Rating Per Characteristic:
10.00 microamperes forward current, average peak
Power Rating Per Characteristic:
400.0 milliwatts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius ambient air
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
2 uninsulated wire lead
Specification Data:
81349-mil-s-19500/436 government specification

Shelf Life: N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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